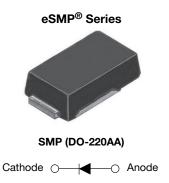


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Vishay Semiconductors

# Ultrafast Rectifier, 1 A FRED Pt®



### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
$V_{R}$	100 V, 200 V			
V <sub>F</sub> at I <sub>F</sub>	0.69 V			
I <sub>FSM</sub>	40 A			
t <sub>rr</sub> (typ.)	23 ns			
T <sub>J</sub> max.	175 °C			
Package	SMP (DO-220AA)			
Circuit configuration	Single			

#### **FEATURES**

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- Low leakage current



- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### TYPICAL APPLICATION

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

### **MECHANICAL DATA**

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002, meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse	VS-1ENH01-M3	V		100	W
voltage	VS-1ENH02-M3	$V_{RRM}$		200	V
Average rectified forward	current	I <sub>F(AV)</sub>	T <sub>C</sub> = 168 °C	1	۸
Non-repetitive peak surge	current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 10 ms sine pulse	40	А
Operating junction and sto	orage temperatures	$T_J$ , $T_{Stg}$		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage,	VS-1ENH01-M3	V <sub>BR</sub> ,	1 100	100	-	-	V
blocking voltage	VS-1ENH02-M3	$V_R$	I <sub>R</sub> = 100 μA	200	-	-	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 1 A	-	0.86	0.92	V
			I <sub>F</sub> = 1 A, T <sub>J</sub> = 150 °C	-	0.69	0.74	
Reverse leakage current		I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	2	μА
			T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	20	
Junction capacitance		C <sub>T</sub>	V <sub>R</sub> = 200 V	-	8	-	pF



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	23	-	
Reverse recovery time	t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	28	
		T <sub>J</sub> = 25 °C	$I_F = 1 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 100 \text{ V}$	-	14	-	ns -
		T <sub>J</sub> = 125 °C		-	22	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.7	-	Α
		T <sub>J</sub> = 125 °C		-	2.7	-	_ ^
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	10	-	nC
	T <sub>J</sub> = 125 °C		-	29	-	110	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Thermal resistance, junction mount		R <sub>thJM</sub> (1)	Infinite heatsink	-	7	9	°C/W	
Thermal resistance, junction to ambient		R <sub>thJA</sub>	PCB footprint 4.8 mm x 4.8 mm	-	107	-	C/VV	
VS-1ENH01-M3			Case style SMP (DO-220AA)	1H1				
Marking device	VS-1ENH02-M3		Case style SiviP (DO-220AA)		11	1H2		

#### Note

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

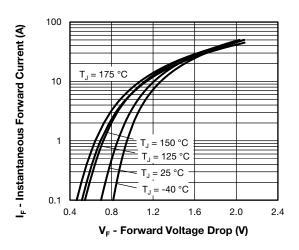


Fig. 1 - Typical Forward Voltage Drop Characteristics

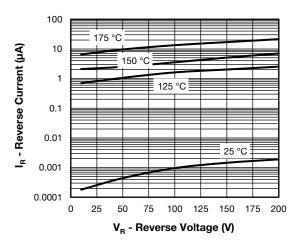


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

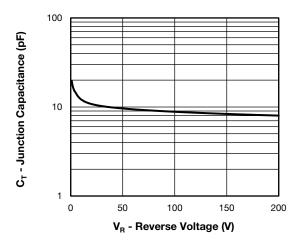


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

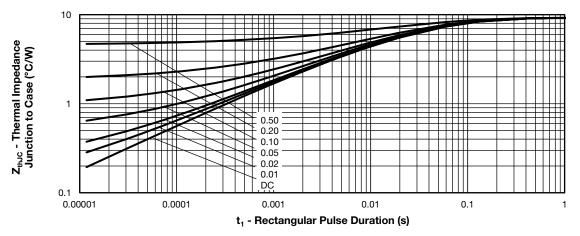


Fig. 4 - Transient Thermal Impedance, Junction to Case

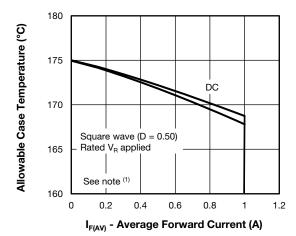


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

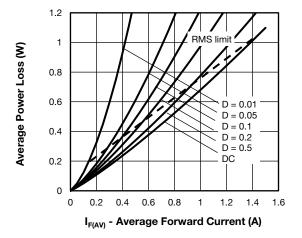
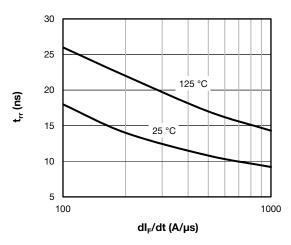
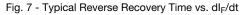


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 5); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>





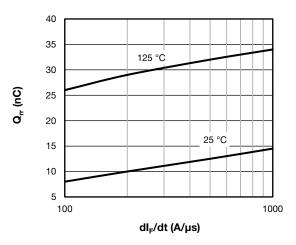
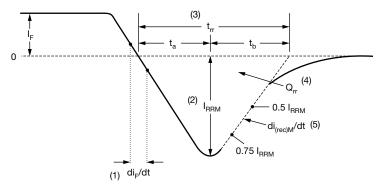


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

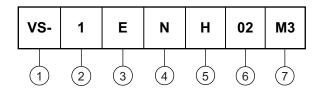
Fig. 9 - Reverse Recovery Waveform and Definitions

## VS-1ENH01-M3, VS-1ENH02-M3

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### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

Current rating (1 = 1 A)

3 - Circuit configuration:

E = single diode

4 - N = SMP package

Process type,

H = ultrafast recovery

6 - Voltage code (02 = 200 V)

7 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

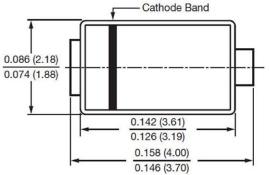
ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-1ENH01-M3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH01-M3/85A	85A	10 000	13" diameter plastic tape and reel			
VS-1ENH02-M3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH02-M3/85A	85A	10 000	13" diameter plastic tape and reel			

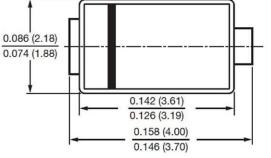
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96547</u>					
Part marking information	www.vishay.com/doc?96574				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96550				

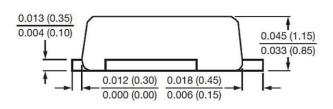


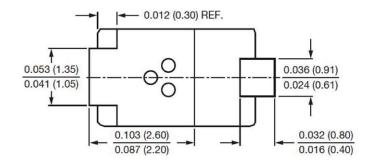
# **SMP (DO-220AA)**

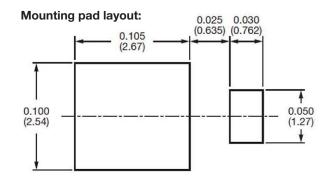
### **DIMENSIONS** in inches (millimeters)













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